Philips Semiconductors

Damper diode ultra fast, high-voltage

BY559X-1500U

FEATURES

- Low forward volt drop
- Low forward recovery voltage
- Ultra Fast switching
- Soft recovery characteristic

GENERAL DESCRIPTION

A double diffused rectifier diode in a plastic envelope, featuring ultra

fast forward and reverse recovery and low forward voltage. The device is intended for use as a damper

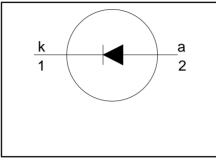
circuits of large screen monitors and workstations in applications up

The BY559 series is supplied in the conventional leaded SOD59 and

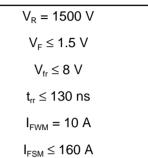
horizontal deflection

- High thermal cycling performance
- Low thermal resistance

SYMBOL

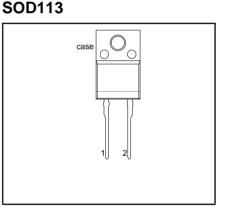


QUICK REFERENCE DATA



PINNING

PIN	DESCRIPTION	
1	cathode	
2	anode	
case	isolated	



LIMITING VALUES

SOD113 packages.

diode in

to 150kHz.

Limiting values in accordance with the Absolute Maximum System (IEC 134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V _{RRM}	Peak repetitive reverse voltage		-	1500	V
V _{RWM}	Crest working reverse voltage		-	1300	V
I _{FWM}	Peak working forward current	f = 120 kHz;	-	10	A
I _{FRM}	Peak repetitive forward current	t = 100 μs	-	150	A
I _{FSM}	Peak non-repetitive forward	t = 10 ms	-	160	A
	current	sinusoidal; $T_i = 150$ °C prior to			
		surge; with reapplied V _{RWM(max)}			
T _{stg}	Storage temperature		-40	150	°C
T	Operating junction temperature		-	150	°C

ISOLATION LIMITING VALUE & CHARACTERISTIC

 $T_{hs} = 25$ °C unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
V _{isol}	R.M.S. isolation voltage from both terminals to external heatsink	f = 50-60 Hz; sinusoidal waveform; R.H. \leq 65% ; clean and dustfree	-		2500	V
C _{isol}	Capacitance from both terminals to external heatsink	f = 1 MHz	-	10	-	pF

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THERMAL RESISTANCES

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
R _{th j-hs}	Thermal resistance junction to heatsink	with heatsink compound	-	-	4.8	K/W
R _{th j-a}		in free air	-	55	-	K/W

STATIC CHARACTERISTICS

 $T_i = 25$ °C unless otherwise stated

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
V _F	Forward voltage	I _F = 6.5 A	-	1.7	2.05	V
	-	I _F = 6.5 A; T _i = 125 °C	-	1.2	1.5	V
I _R	Reverse current	$V_{R} = V_{RWMmax}$	-	-	0.5	mA
		$V_R = V_{RWMmax}; T_j = 125 \degree C$	-	-	2.0	mA

DYNAMIC CHARACTERISTICS

 $T_i = 25$ °C unless otherwise stated

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
$\begin{matrix} V_{fr} \\ t_{fr} \\ t_{rr} \\ Q_{s} \end{matrix}$	Forward recovery voltage Forward recovery time Reverse recovery time Reverse recovery charge	$ I_{F} = 6.5 \text{ A}; \ dI_{F}/dt = 50 \text{ A}/\mu \text{s} \\ I_{F} = 6.5 \text{ A}; \ dI_{F}/dt = 50 \text{ A}/\mu \text{s}; \ V_{F} = 5 \text{ V} \\ I_{F} = 1 \text{ A}; \ dI_{F}/dt = 50 \text{ A}/\mu \text{s}; \ V_{R} \ge 30 \text{ V} \\ I_{F} = 2 \text{ A}; \ dI_{F}/dt = 20 \text{ A}/\mu \text{s}; \ V_{R} \ge 30 \text{ V} $	-	6 130 100 0,2	8 180 130 0,3	V ns ns uC

F

10%

 $^{\sf V}{}_{\sf F}$

'_F

I R

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tfr

– dl _F

dt

Qs

Fig.1. Definition of Vfr and tfr

trr

time

5[']V / 2V

time

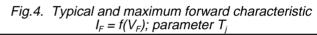
time

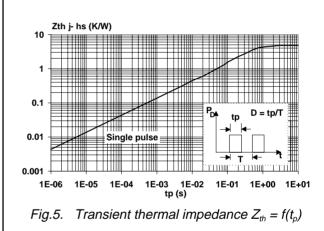
100%

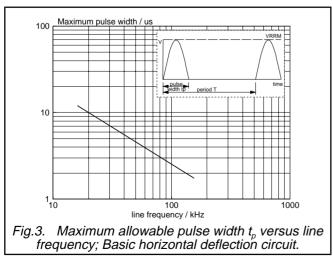
V F

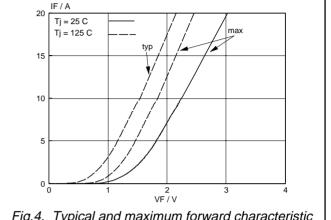
25%

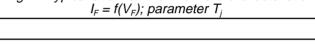
IF / A 20 Tj = 25 C Tj = 125 C max typ 15 10 5 0 2 VF / V 3

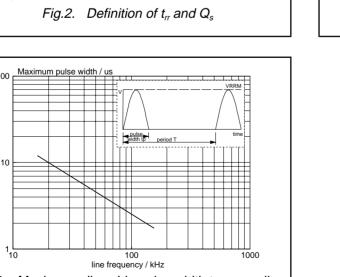










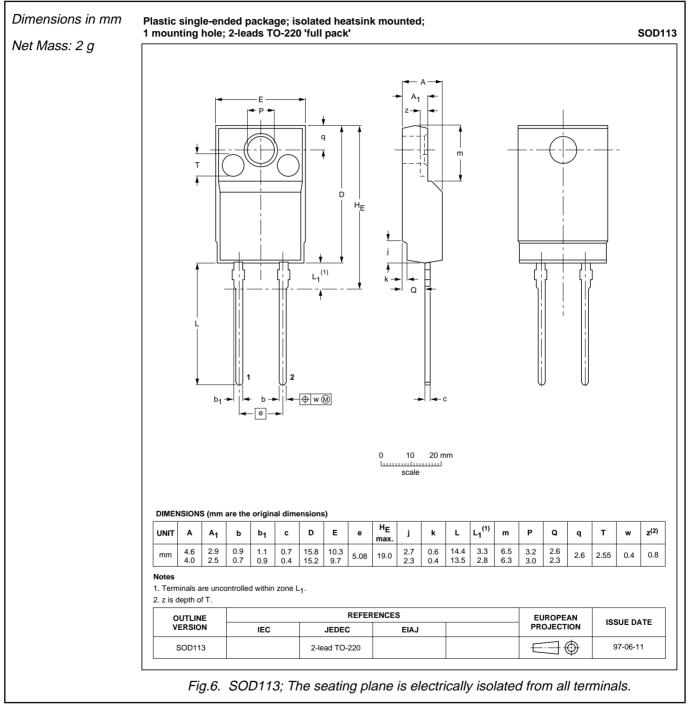




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MECHANICAL DATA



Notes

Refer to mounting instructions for F-pack envelopes.
Epoxy meets UL94 V0 at 1/8".

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DEFINITIONS

Data sheet status				
Objective specification This data sheet contains target or goal specifications for product development.				
Preliminary specification	ry specification This data sheet contains preliminary data; supplementary data may be published later.			
Product specification	This data sheet contains final product specifications.			
Limiting values				
Limiting values are given in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of this specification is not implied. Exposure to limiting values for extended periods may affect device reliability.				
Application information				
Where application information is given, it is advisory and does not form part of the specification.				
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